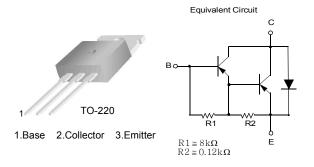


October 2008

# **TIP125/TIP126/TIP127 PNP Epitaxial Darlington Transistor**

- · Medium Power Linear Switching Applications
- Complementary to TIP120/121/122



## Absolute Maximum Ratings\* $T_a = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Ratings	Units
V <sub>CBO</sub>	Collector-Base Voltage : TIP125	- 60	V
	: TIP126	- 80	V
	: TIP127	- 100	V
	Collector-Emitter Voltage : TIP125	- 60	V
V <sub>CEO</sub>	: TIP126	- 80	V
	: TIP127	- 100	V
V <sub>EBO</sub>	Emitter-Base Voltage	- 5	V
I <sub>C</sub>	Collector Current (DC)	- 5	А
I <sub>CP</sub>	Collector Current (Pulse)	- 8	А
I <sub>B</sub>	Base Current (DC)	- 120	mA
P <sub>C</sub>	Collector Dissipation (T <sub>a</sub> =25°C)	2	W
	Collector Dissipation (T <sub>C</sub> =25°C)	65	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 65 ~ 150	°C

<sup>\*</sup> These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

### **Electrical Characteristics\*** T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V <sub>CEO</sub> (sus)	Collector-Emitter Sustaining Voltage : TIP125 : TIP126 : TIP127	I <sub>C</sub> = -100mA, I <sub>B</sub> = 0	-60 -80 -120			V V V
ICEO	Collector Cut-off Current : TIP125 : TIP126 : TIP127	$V_{CE} = -30V, I_{B} = 0$ $V_{CE} = -40V, I_{B} = 0$ $V_{CE} = -50V, I_{B} = 0$			-2 -2 -2	mA mA mA
I <sub>CBO</sub>	Collector Cut-off Current : TIP125 : TIP126 : TIP127	$V_{CB} = -60V, I_{E} = 0$ $V_{CB} = -80V, I_{E} = 0$ $V_{CB} = -100V, I_{E} = 0$			-1 -1 -1	mA mA mA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{BE} = -5V, I_{C} = 0$			-2	mA
h <sub>FE</sub>	* DC Current Gain	$V_{CE} = -3V, I_{C} = 0.5A$ $V_{CE} = -3V, I_{C} = -3A$	1000 1000			
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage	$I_C = -3A$ , $I_B = -12mA$ $I_C = -5A$ , $I_B = -20mA$			-2 -4	V V
V <sub>BE</sub> (on)	* Base-Emitter On Voltage	$V_{CE} = -3V, I_{C} = -3A$			-2.5	V
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = -10V, I <sub>E</sub> = 0, f = 0.1MHz			300	pF

<sup>\*</sup> Pulse Test: Pulse Width≤300µs, Duty Cycle≤2%

## **Typical Characteristics**

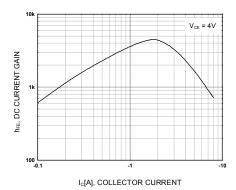


Figure 1. DC current Gain

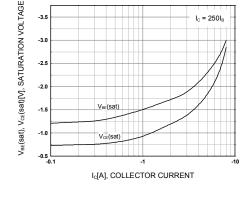


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

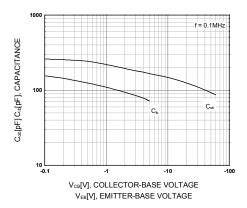


Figure 3. Output and Input Capacitance vs. Reverse Voltage

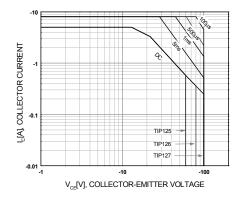


Figure 4. Safe Operating Area

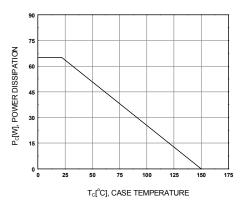
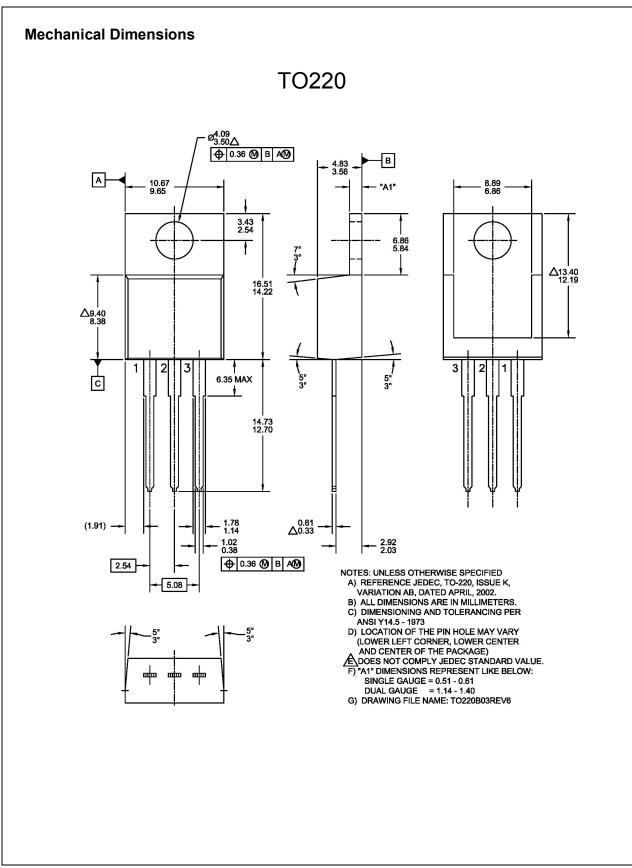


Figure 5. Power Derating







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